Specifications

LV52130N0XA DEFAULT: VOUT1=+5V, VOUT2=-5V

MARKING: 130NX YMXX

LV52130N4XA DEFAULT: VOUT1=+5.4V, VOUT2=-5.4V

MARKING: 130N4 YMXX

Absolute Maximum Ratings at Ta = 25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|----------|-------------------------------|-------------|------|
| Maximum supply voltage | VINmax | VIN to GNDs | +6 | V |
| Maximum Pin voltage1 | Vpin1max | CN,VOUT2 to GNDs | -6 | V |
| Maximum Pin voltage2 | Vpin2max | LX | +7 | V |
| Maximum Pin voltage3 | Vpin3max | Other pin to GNDs | +6 | V |
| Allowable power dissipation | Pdmax | Ta=25°C The specified board*1 | 1 | W |
| Operating temperature | Topr | | -40 to +85 | °C |
| Storage temperature | Tstg | | -55 to +125 | °C |

^{*1} Mounted on a specified board: 50mm×50mm×1mm (2 layer glass epoxy)

Caution 1) Absolute maximum ratings represent the values which cannot be exceeded for any length of time.

Caution 2) Even when the device is used within the range of absolute maximum ratings, as a result of continuous usage under high temperature, high current, high voltage, or drastic temperature change, the reliability of the IC may be degraded. Please contact us for the further details.

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Recommended Operating Conditions at Ta = 25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|----------------------|--------------------|------------|------------|------|
| Supply voltage range | V _{IN op} | VIN | 2.5 to 5.5 | V |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

Electrical Characteristics

at Ta = 25°C, PVIN=VIN=3.7V VOUT1=5V VOUT2=-5V (Unless otherwise noted)

| Danamatan | O. mala al | Conditions | | Lloit | | |
|-----------------------------|------------|-------------------|-----|-------|-----|------|
| Parameter | Symbol | Conditions | min | typ | max | Unit |
| VIN current | | | | | | |
| Standby current dissipation | ICC1 | IC disable | | 8.5 | | uA |
| VBST DCDC Converter | | | | | | |
| VBST current limit | ICLBST | LX | 0.9 | 1.2 | 1.5 | Α |
| VOUT1 LDO | | | | | | |
| VOUT1 voltage | VOUT1 | Default | | 5 | | V |
| VOUT1 voltage range | VOUT1 | 100mVsteps by I2C | 4.1 | | 5.7 | ٧ |
| VOUT1 voltage accuracy | VOUT1 | | -1 | | 1 | % |
| VOUT1 dropout voltage | Vdrop | 150mA | | 150 | | mV |
| VOUT1 current | IOUT1 | IOUT2=0 | | | 200 | mA |
| VOUT1 line regulation | VLINR1 | dVo=1V Io=30mA | | 0.3 | | %/V |
| VOUT1 load regulation | VLDR1 | lo=2mA/150mA | | 4 | | mV |
| Discharge Resistance 1 | RVO1 | | | 70 | | Ω |
| Soft-start | tssvo1 | | | 0.2 | | ms |

Continued on next page

Continued from preceding page

| ı | | 1 | | | | |
|--------------------------------|---|---|---|-------|--------|--|
| Symbol | Symbol | | Ratings | | | |
| Symbol | Conditions | min | typ | max | Unit | |
| | | | | | | |
| VOUT2 | Default | | -5 | | V | |
| VOUT2R | 100mV steps by I2C | -5.7 | | -4.1 | V | |
| VOUT2A | | -1 | | 1 | % | |
| IOUT2 | IOUT1=0 | | | 100 | mA | |
| VLINR2 dVo=1V lo=30mA | | | 0.3 | | %/V | |
| VLDR2 lo=2mA/60mA | | | 20 | | mV | |
| Resistance 2 RVO2 | | | 20 | | Ω | |
| Soft-start tssvo2 | | | 0.2 | | ms | |
| | | | | | | |
| Fosc1 | Boost-DCDC | 1.48 | 1.85 | 2.22 | MHz | |
| Fosc2 | charge pump | 0.74 | 0.925 | 1.11 | MHz | |
| | | | | | | |
| Vuvlo_h | VIN up | | | 2.5 | V | |
| Vuvlo_I | VIN down | | | 2.3 | V | |
| | | | · | | | |
| VINH | SDA/SCL/EN1/EN2 | 1.26 | · | VIN | V | |
| VINL | SDA/SCL/EN1/EN2 | 0 | | 0.54 | V | |
| Pulldown Resistance Rpd EN1/El | | | 400 | | kΩ | |
| | VOUT2R VOUT2A IOUT2 VLINR2 VLDR2 RVO2 tssvo2 Fosc1 Fosc2 Vuvlo_h Vuvlo_I VINH VINL | VOUT2 Default VOUT2R 100mV steps by I2C VOUT2A IOUT1=0 IOUT2 IOUT1=0 VLINR2 dVo=1V Io=30mA VLDR2 Io=2mA/60mA RVO2 tssvo2 Fosc1 Boost-DCDC Fosc2 charge pump Vuvlo_h VIN up Vuvlo_I VIN down VINH SDA/SCL/EN1/EN2 VINL SDA/SCL/EN1/EN2 | VOUT2 Default VOUT2R 100mV steps by I2C -5.7 VOUT2A -1 IOUT2 IOUT1=0 VLINR2 dVo=1V Io=30mA VLDR2 Io=2mA/60mA RVO2 tssvo2 Fosc1 Boost-DCDC 1.48 Fosc2 charge pump 0.74 Vuvlo_h VIN up Vuvlo_I Vuvlo_I VIN down 1.26 VINL SDA/SCL/EN1/EN2 0 | VOUT2 | Nounce | |

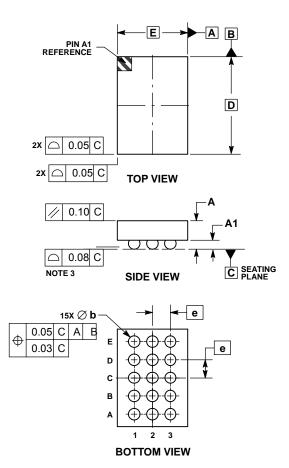
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Package Dimensions

unit : mm

WLCSP15, 2.15x1.55 CASE 567HY

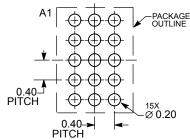
ISSUE A



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. COPLANARITY APPLIES TO SPHERICAL CROWNS OF SOLDER BALLS.

| | MILLIMETERS | | | | | |
|-----|-------------|-------|--|--|--|--|
| DIM | MIN | MAX | | | | |
| Α | | 0.625 | | | | |
| A1 | 0.16 | 0.26 | | | | |
| b | 0.20 | 0.30 | | | | |
| D | 2.15 | BSC | | | | |
| E | 1.55 BSC | | | | | |
| е | 0.40 | BSC | | | | |

RECOMMENDED SOLDERING FOOTPRINT*

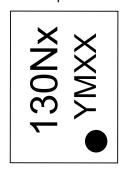


DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

LV52130N0XA/LV52130N4XA is as follows.

MARKING DIAGRAM Top view



= Device Mark XX = Assembly lot Code

Block Diagram

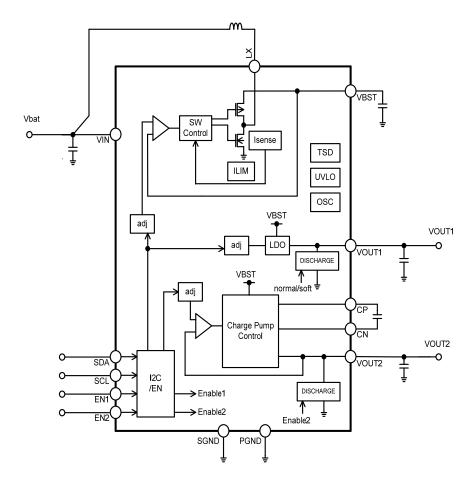


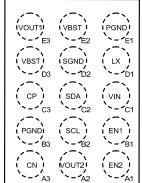
Fig.2 Block Diagram

Pin Function

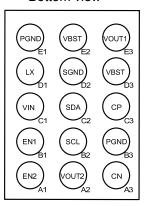
| I III I UIICUOII | | |
|------------------|----------|---|
| PIN# | Pin Name | Description |
| A1 | EN2 | Enable1 input pin |
| A2 | VOUT2 | VOUT2 output pin |
| A3 | CN | Flying capacitor connection pin for charge pump |
| B1 | EN1 | Enable1 input pin |
| B2 | SCL | I2C clock signal input pin |
| B3/E1 | PGND | Power Ground |
| C1 | VIN | Power supply voltage |
| C2 | SDA | I2C data signal input / output pin |
| С3 | СР | Flying capacitor connection pin for charge pump |
| D1 | LX | Boost converter switching pin |
| D2 | SGND | Signal Ground |
| D3/E2 | VBST | Boost converter direct output pin |
| E3 | VOUT1 | VOUT1 output pin |

PIN CONNECTIONS

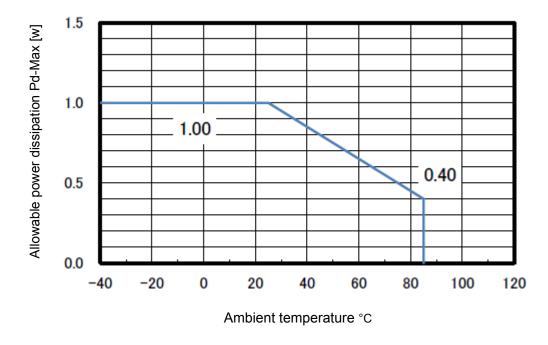




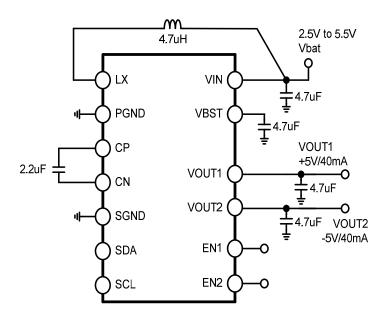
Bottom view



Pd-Max



Mounted on a specified board: 50mm×50mm×1mm (2 layer glass epoxy)



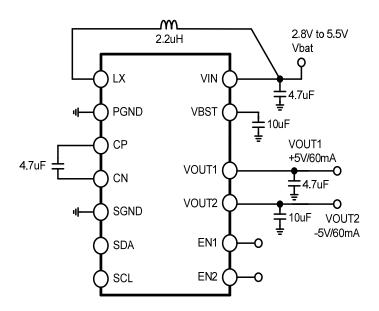


Fig.3 Recommendation Applications

Table . Component List for Typical Characteristics Circuit

| | Table : Component List for Typicar | Characteristics Circuit |
|-----------|---------------------------------------|------------------------------|
| Reference | Description | Manufacturer and Part Number |
| | 2.2µF, +-10%, 10V, X5R, ceramic | TDK - C1608X5R1A225K |
| С | 4.7μF, +-10%, 10V, X5R, ceramic | TDK - C1608X5R1A475K |
| | 10μF, +-10%, 10V, X5R, ceramic | TDK - C1608X5R1A106K |
| | 2.2μH, 1.1A, 120mΩ, 2.5mm×2.0mm×1.1mm | TDK - MLP2520V2R2ST0S1 |
| L | 4.7μH, 0.8A, 220mΩ, 2.5mm×2.0mm×1.1mm | TDK - MLP2520V4R7ST0S1 |

BITMAP (I2C control) / I2C disable at standby

WRITE: IC Address: 0111110x x=0:Write mode / x=1:inhibition

| | Sub | MSB | | | | | | | LSB |
|-------|-----------|-----|-----|-----|-------|-------|-------|--------|--------|
| | Address | (7) | (6) | (5) | (4) | (3) | (2) | (1) | (0) |
| VOUT1 | 0000 0000 | - | - | - | VOUT1 | VOUT1 | VOUT1 | VOUT1 | VOUT1 |
| VOUT2 | 0000 0001 | - | - | - | VOUT2 | VOUT2 | VOUT2 | VOUT2 | VOUT2 |
| Mode | 0000 0011 | | | | | | | No use | No use |

NOTE: About Sub address "0000 0011"

Prohibit data's setting "0" of DATA (0) and DATA (1).

| bits | VOUT1 [V] | VOUT2 [V] |
|------|-----------|-----------|
| 0 | not use | not use |
| 1 | 4.1 | -4.1 |
| 2 | 4.2 | -4.2 |
| 3 | 4.3 | -4.3 |
| 4 | 4.4 | -4.4 |
| 5 | 4.5 | -4.5 |
| 6 | 4.6 | -4.6 |
| 7 | 4.7 | -4.7 |
| 8 | 4.8 | -4.8 |
| 9 | 4.9 | -4.9 |
| 10 | 5.0* | -5.0* |
| 11 | 5.1 | -5.1 |
| 12 | 5.2 | -5.2 |
| 13 | 5.3 | -5.3 |
| 14 | 5.4** | -5.4** |
| 15 | 5.5 | -5.5 |
| 16 | 5.6 | -5.6 |
| 17 | 5.7 | -5.7 |

^{* :}default = +-5V (LV52130N0XA)

^{** :}default = +-5.4V (LV52130N4XA)

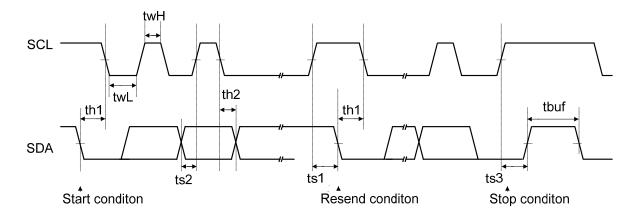
Serial Bus Communication Specifications Standard mode

| Parameter | symbol | Conditions | min | typ | max | unit |
|---------------------|--------|--|-----|-----|------|------|
| SCL clock frequency | fscl | SCL clock frequency | 0 | - | 100 | kHz |
| Data set up time | ts1 | SCL setup time relative to the fall of SDA | 4.7 | - | - | μs |
| | ts2 | SDA setup time relative to the rise of SCL | 250 | - | - | ns |
| | ts3 | SCL setup time relative to the rise of SDA | 4.0 | - | - | μs |
| Data hold time | th1 | SCL data hold time relative to the rise of SDA | 4.0 | - | - | μs |
| | th2 | SDA hold time relative to the fall of SCL | 0 | - | - | μs |
| Pulse width | twL | SCL pulse width for the L period | 4.7 | - | - | μs |
| | twH | SCL pulse width for the H period | 4.0 | - | - | μs |
| Input waveform | ton | SCL and SDA (input) rise time | - | - | 1000 | ns |
| conditions | tof | SCL and SDA (input) fall time | - | - | 300 | ns |
| Bus free time | tbuf | Time between STOP and START conditions | 4.7 | - | - | μs |

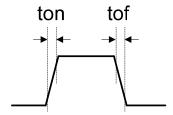
High-speed mode

| Parameter | Symbol | Conditions | min | typ | max | unit |
|---------------------|--------|--|-----|-----|-----|------|
| SCL clock frequency | fscl | SCL clock frequency | 0 | - | 400 | kHz |
| Data setup time | ts1 | SCL setup time relative to the fall of SDA | 0.6 | - | - | μs |
| | ts2 | SDA setup time relative to the rise of SCL | 100 | - | - | ns |
| | ts3 | SCL setup time relative to the rise of SDA | 0.6 | - | - | μs |
| Data hold time | th1 | SCL data hold time relative to the rise of SDA | 0.6 | - | - | μs |
| | th2 | SDA hold time relative to the fall of SCL | 0 | - | - | μs |
| Pulse width | twL | SCL pulse width for the L period | 1.3 | - | - | μs |
| | twH | SCL pulse width for the H period | 0.6 | - | - | μs |
| Input waveform | ton | SCL and SDA (input) rise time | - | - | 300 | ns |
| conditions | tof | SCL and SDA (input) fall time | - | - | 300 | ns |
| Bus free time | tbuf | Time between STOP and START conditions | 1.3 | - | - | μs |

I²C serial transfer timing conditions

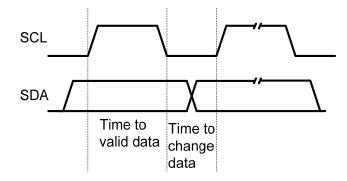


Input waveform condition



I²C control transmission method

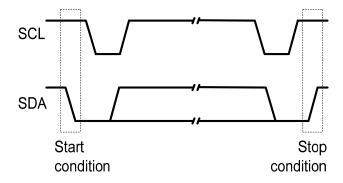
In start and stop conditions of the I²C bus, SDA should be kept in the constant state while SCL is "H" as shown below during data transfer.



When data transfer is not made, both SCL and SDA are in the "H" state.

When SCL = SDA="H", change of SDA from "H" to "L" enables the start conditions to start access.

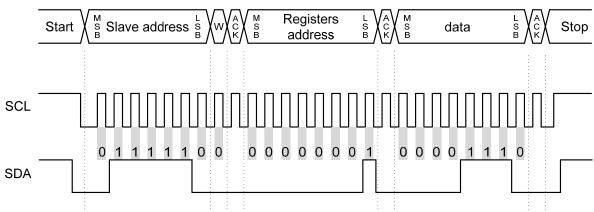
When SCL is "H", change of SDA from "L" to "H" enables the stop conditions to stop access.



Data transfer and acknowledgement response

After establishment of start conditions, Data transfer is made by one byte (8 bits). Data transfer enables continuous transfer of any number of bytes. Each time of the 8-bit data is transferred, the ACK signal is sent from the receive side to the send side. The ACK signal is issued when SDA(on the send side) is released and SDA(on the receive side) is set "L" immediately after fall of the clock pulse at the SCL eighth bit of data transfer to "L". When the next 1-byte transfer is left in the receive state after transmission of the ACK signal from the receive side, the receive side releases SDA at fall of the SCL ninth clock. In the I2C bus, there is no CE signal. Instead, 7-bit slave address is assigned to each device and the first byte of transfer is assigned to the command (R/W) representing the 7-bit slave address and subsequent transfer direction. Note that only WRITE is valid in this IC. The 7-bit address is transferred sequentially from MSB and the eighth bit is "L" representing WRITE.

Input 1data



Input 2data (register address auto Increment)

| Start | Slave address s | \\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\ | M Registers address B 0000 0000 | L S C K | S S | L S B K M S B | Data VOUT2 | L S B K | Stop |
|-------|-----------------|--|---------------------------------|------------------|-----|---------------------------------|---------------|------------------|------|
|-------|-----------------|--|---------------------------------|------------------|-----|---------------------------------|---------------|------------------|------|

Detailed Descriptions

The LV52130Nx has dual-output VOUT1 (LDO) and VOUT2 (built-in inverter charge pump) with 1coil boost dcdc converter. Both outputs are separately controlled by I2C control and pin EN1/EN2. Boost converter is a fixed-frequency pulse width modulated (PWM) regulator. At rated load, each converter operates at continuous conduction mode (CCM). At light loads, both converters can enter in discontinuous conduction mode (DCM). Cycle-by-cycle peak current limit and thermal provide value added features to protect the device.

Inductor Selection

Three different electrical parameters need to be considered when selecting an inductor, the value of the inductor, the saturation current and the DCR. During normal and heavy load operation, the LV52130Nx is intended to operate in Continuous Conduction Mode (CCM). The equation below can be used to calculate the peak current.

$$Ipeak_p = Iout1 / (n1 x (1-D1)) + (VIN x D1) / 2 x L1 x Fosc1$$

VIN:battery voltage, IOUT1:load current, L:inductor value, Fosc1: OSC frequency1, D1:duty cycle, n1:converter efficiency varies with load current.

A good approximation is to use $\eta=0.85$. It is important to ensure that the inductor current rating is high enough such that it not saturate. As the inductor size is reduced, the peak current for a given set of conditions increases along with higher current ripple so it is not possible to deliver maximum output power at lower inductor values. Finally an acceptable DCR must be selected regarding losses in the coil and must be lower than 250 m Ω (typical) to limit excessive voltage drop. In addition, as DCR is reduced, overall efficiency will improve. The inductor value is recommended to use a 4.7 μ H or 2.2 μ H.

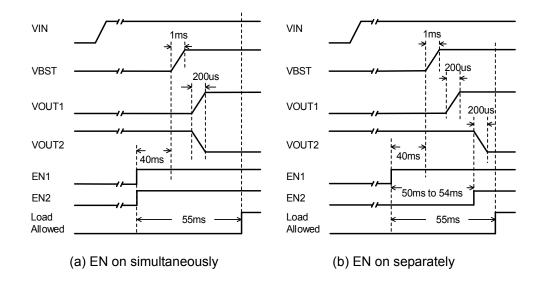
POR function

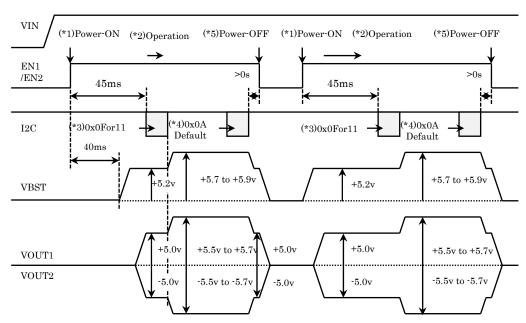
This is "Power On Reset" function to reset internal logic circuits which include SCP's latch. This function can be worked by reducing IC's VIN voltage until about 1V.

Start/Shutdown Sequencing

Enable input (pin EN1/EN2) is used as enable input logic. An active high logic level on this pin enables the device. A built-in pull-down resistor disables the device if the pin is left open. If a high logic signal is applied, the LV52130Nx starts with timing sequence as depicted Figure 4. It must be kept below points in the start/shutdown sequence for stable operation.

- When Vout set $5.5V \ge VOUT1 / VOUT2 \le -5.5V$, please change to its voltage 45msec later.
- ✓ About shutdown, please send default (5.0V/5.4V) data by IIC before EN=OFF.
- ✓ The each load current of VOUT1 and VOUT2 while startup is only charging current for the each external capacitor (4.7μF).
- ✓ IC needs 55msec waiting time from the EN1 until loading of panel module.
- ✓ Keep each the H/L levels at lease 1msec





#1 Operation to Power ON
Power ON (EN1/EN2:Hi)(*1)
Operation after 45ms (Until VOUT1&2 becomes stable)(*2)
Data send (5.5V or 5.7V)(*3)

#2 Operations to Power OFF Data send (5.0V)(*4) Power OFF (EN1/EN2:Lo)(*5)

(c) In the case of LV52130N0XA-VH

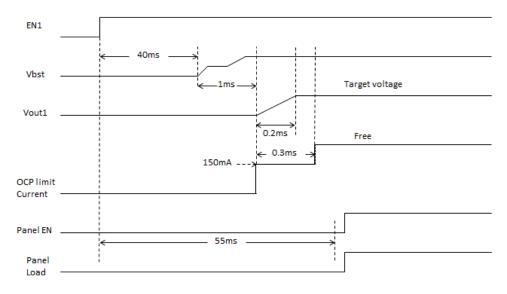
Fig.4 Sequencing Diagram

OCP and SCP function

IC has OCP and SCP function and the behavior is shown in figures below.

(1) OCP limit transition in normal operation

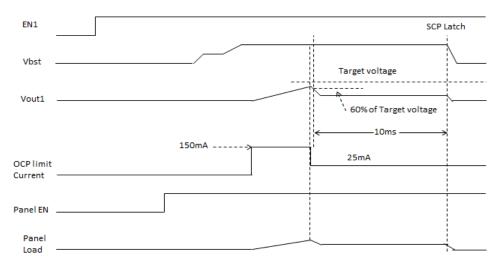
The OCP means "Over Current Protection" and is equipped for preventing excessive inrush current about Vout1. It watches for limit of 150mA during 300usec from ramp up of Vout1, and then changes almost free.



(1). Transition of OCP limit current in start sequence

(2) Heavy load of during ramp up

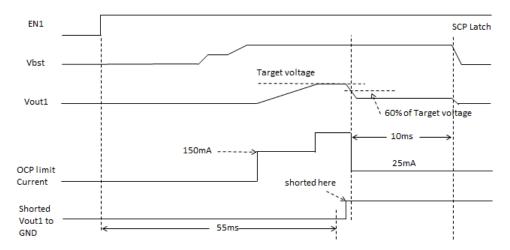
If vout1 voltage doesn't reach target voltage at the end of time of the 300usec, then IC is doubtful of excessive current load and changes the limit to 25mA. This small current is held until recovery of the Vout1 voltage. By way of example of a case, if high load current like as 25ohm that is bigger than 150mA current capacity of Vout1 comes during ramp up term and after 300usec at Vout1, then IC chooses 25mA mode which is defeated the load. As a result, IC goes to off with latch and requires VIN's re-installation. As it was mentioned in Start/Shutdown Sequencing section above, the 55msec waiting time is needed to avoid the case.



(2). Transition of OCP limit current in start sequence at abnormal case

(3) SCP function

The SCP means "Short Circuit Protection". This is used to protect each Vout when they are connected to the GND. SCP function becomes active when Vout voltage reaches under 60% of its target voltage. Once SCP is activated, the counter begins to count 10msec. If the SCP detection is active for full 10msec, IC then gets shut down and latch. On the other hand, if the Vout voltage is recovered within this 10msec IC will reactivate. This latch is released by dropping VIN.



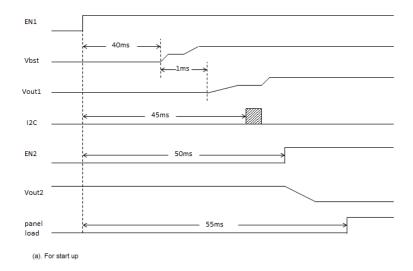
(3). Transition of OCP limit current in start sequence at shorted circuit to GND case

Startup shutdown sequence summary

When Vout set 5.5V ≥ VOUT1 / VOUT2 ≤ -5.5V

For start up

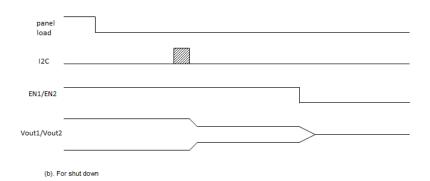
- (1) EN1=H;
- (2) 45msec later, send I2C wish data;
- (3) After 50msec from (1), EN2=H;
- (4) 55msec later, start panel load;



For shut down

- (1) stop panel load
- (2) send I2C data of 0x0A;
- (3) EN1 and EN2 = L;

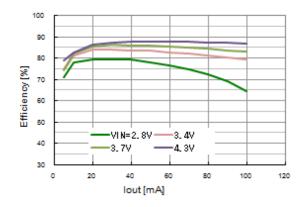
Note: Need spacing over 1ms until the next EN1=H or EN2=H from "(3) EN1 and EN2=L".



TYPICAL OPERATING CHARACTERISTICS

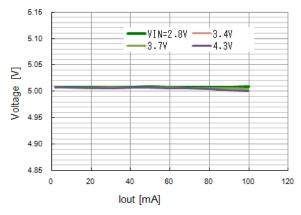
Efficiency

VOUT1=5V, VOUT2=-5V (lout=VOUT1 to VOUT2) Cvout1=4.7 μ F, Cvout2=4.7 μ F, Cbst=4.7 μ F, Ccp_cn=2.2 μ F, Cvin=10 μ F+4.7 μ F, L=4.7 μ H



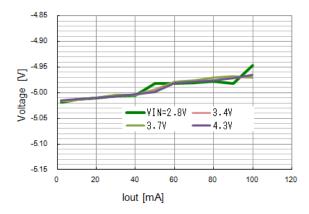
Load Regulation VOUT1

VOUT1=5V, VOUT2=-5V (lout=VOUT1 to VOUT2) Cvout1=4.7μF, Cvout2=4.7μF, Cbst=4.7μF, Ccp_cn=2.2μF, Cvin=10μF+4.7μF, L=4.7μH



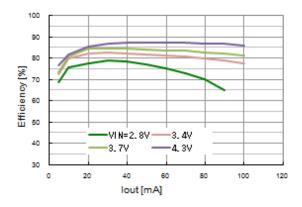
Load Regulation VOUT2

VOUT1=5V, VOUT2=-5V (lout=VOUT1 to VOUT2) Cvout1=4.7µF, Cvout2=4.7µF, Cbst=4.7µF, Ccp_cn=2.2µF, Cvin=10µF+4.7µF, L=4.7µH



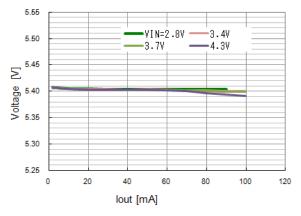
Efficiency

VOUT1=5.4V, VOUT2=-5.4V (lout=VOUT1 to VOUT2) Cvout1=4.7μF, Cvout2=4.7μF, Cbst=4.7μF, Ccp_cn=2.2μF, Cvin=10μF+4.7μF, L=4.7μH



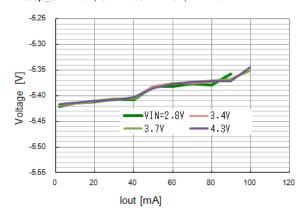
Load Regulation VOUT1

VOUT1=5.4V, VOUT2=-5.4V (lout=VOUT1 to VOUT2) Cvout1=4.7 μ F, Cvout2=4.7 μ F, Cbst=4.7 μ F, Ccp_cn=2.2 μ F, Cvin=10 μ F+4.7 μ F, L=4.7 μ H



Load Regulation VOUT2

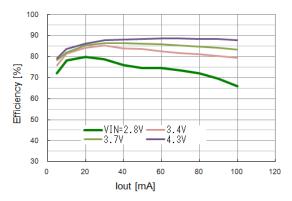
VOUT1=5.4V, VOUT2=-5.4V (lout=VOUT1 to VOUT2) Cvout1=4.7uF, Cvout2=4.7uF, Cbst=4.7uF, Ccp_cn=2.2uF, Cvin=10uF+4.7uF, L=4.7uH



TYPICAL OPERATING CHARACTERISTICS

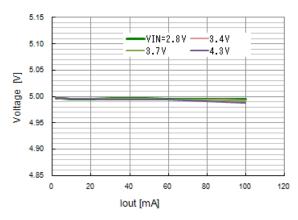
Efficiency

VOUT1=5V, VOUT2=-5V (lout=VOUT1 to VOUT2) Cvout1=4.7µF, Cvout2=10µF, Cbst=10µF, Ccp_cn=4.7µF, Cvin=10µF+4.7µF, L=2.2µH



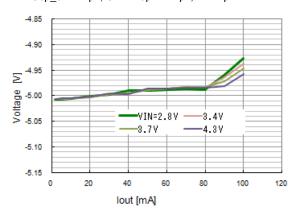
Load Regulation VOUT1

VOUT1=5V, VOUT2=-5V (lout=VOUT1 to VOUT2) Cvout1=4.7µF, Cvout2=10µF, Cbst=10µF, Ccp_cn=4.7µF, Cvin=10µF+4.7µF, L=2.2µH



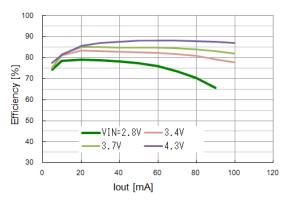
Load Regulation VOUT2

VOUT1=5V, VOUT2=-5V (lout=VOUT1 to VOUT2) Cvout1=4.7µF, Cvout2=10µF, Cbst=10µF, Ccp_cn=4.7µF, Cvin=10µF+4.7µF, L=2.2µH



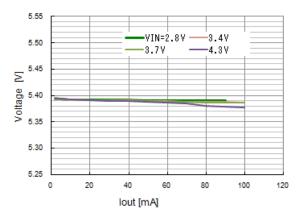
Efficiency

VOUT1=5.4V, VOUT2=-5.4V (lout=VOUT1 to VOUT2) Cvout1=4.7μF, Cvout2=10μF, Cbst=10μF, Ccp cn=4.7μF, Cvin=10μF+4.7μF, L=4.7μH



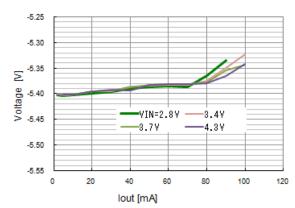
Load Regulation VOUT1

VOUT1=5.4V, VOUT2=-5.4V (lout=VOUT1 to VOUT2) Cvout1=4.7μF, Cvout2=10μF, Cbst=10μF, Ccp_cn=4.7μF, Cvin=10μF+4.7μF, L=4.7μH



Load Regulation VOUT2

VOUT1=5.4V, VOUT2=-5.4V (lout=VOUT1 to VOUT2) Cvout1=4.7μF, Cvout2=10μF, Cbst=10μF, Ccp_cn=4.7μF, Cvin=10μF+4.7μF, L=4.7μH



ORDERING INFORMATION

| Device | Package | Shipping (Qty / Packing) |
|----------------|--------------------------------|--------------------------|
| LV52130N0XA-VH | WLP15 (1.55×2.15) (Pb-Free) | 4000 / Tape & Reel |
| LV52130N4XA-VH | WLP15 (1.55×2.15) (Pb-Free) | 4000 / Tape & Reel |

[†] For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. http://www.onsemi.com/pub_link/Collateral/BRD8011-D.PDF

ON Semiconductor and the ON logo are registered trademarks of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries. SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent re